

DA03-11EWA/SRWA/YWA/GWA  
DC03-11EWA/SRWA/YWA/GWA

### Features

- 0.3 INCH DIGIT HEIGHT.
- LOW CURRENT OPERATION.
- EXCELLENT CHARACTER APPEARANCE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- TWO DIGIT PACKAGE SIMPLIFIES ALIGNMENTS & ASSEMBLY.
- I.C. COMPATIBLE.
- CATEGORIZED FOR LUMINOUS INTENSITY, YELLOW AND GREEN CATEGORIZED COLOR.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE SEGMENT.

### Description

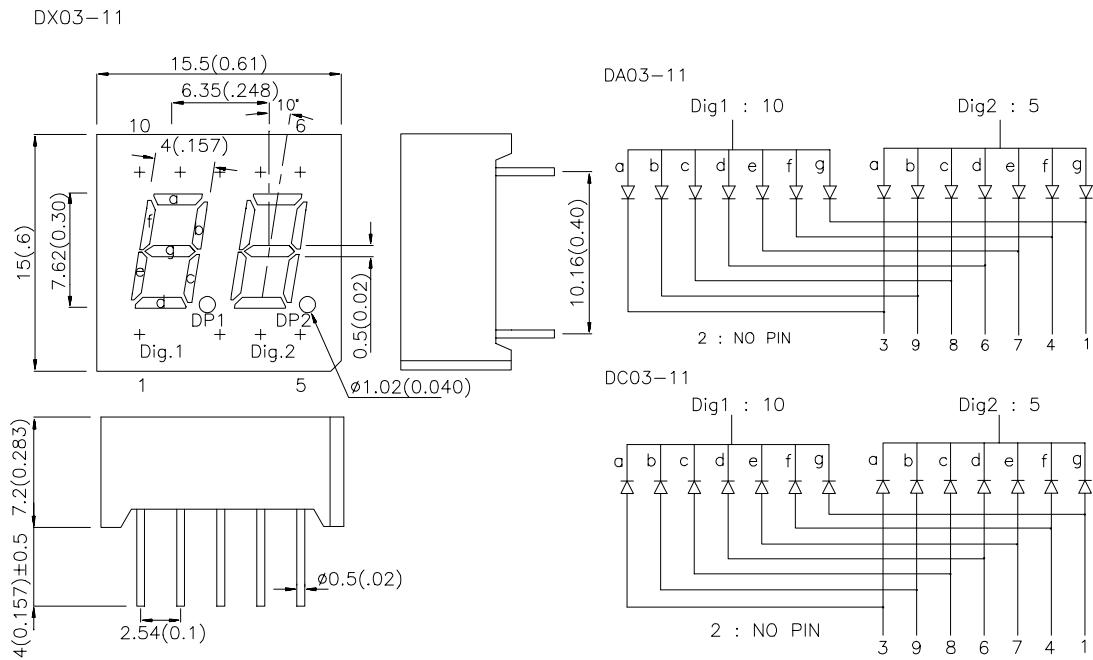
The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

The Super Bright Red source color devices are made with Gallium Aluminum Arsenide Red Light Emitting Diode.

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

### Package Dimensions & Internal Circuit Diagram



**Notes:**

1. All dimensions are in millimeters (inches), Tolerance is  $\pm 0.25(0.01)$  unless otherwise noted.
2. Specifications are subject to change without notice.

## Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) @ 10 mA		Description
			Min.	Typ.	
DA03-11EWA	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	800	1900	Common Anode
DC03-11EWA					Common Cathode
DA03-11SRWA	SUPER BRIGHT RED (GaAlAs)	WHITE DIFFUSED	3000	8000	Common Anode
DC03-11SRWA					Common Cathode
DA03-11YWA	YELLOW (GaAsP/GaP)	WHITE DIFFUSED	480	1200	Common Anode
DC03-11YWA					Common Cathode
DA03-11GWA	GREEN (GaP)	WHITE DIFFUSED	1200	3000	Common Anode
DC03-11GWA					Common Cathode

## Electrical / Optical Characteristics at T<sub>A</sub>=25°C

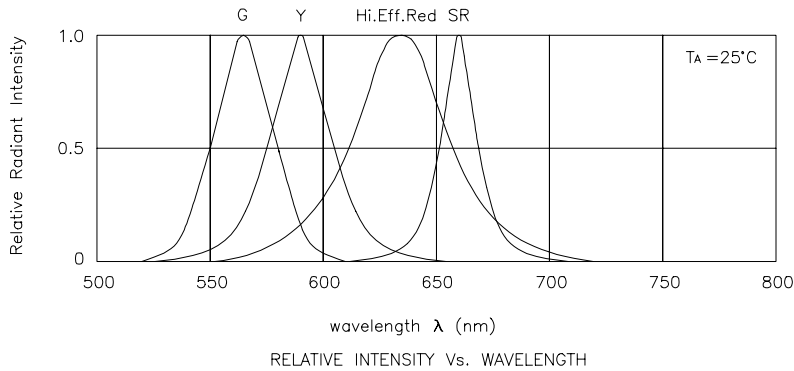
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
$\lambda_{peak}$	Peak Wavelength	High Efficiency Red Super Bright Red Yellow Green	627 660 590 565		nm	I <sub>F</sub> =20mA
$\lambda_D$	Dominant Wavelength	High Efficiency Red Super Bright Red Yellow Green	625 640 588 568		nm	I <sub>F</sub> =20mA
$\Delta\lambda/2$	Spectral Line Half-width	High Efficiency Red Super Bright Red Yellow Green	45 20 35 30		nm	I <sub>F</sub> =20mA
C	Capacitance	High Efficiency Red Super Bright Red Yellow Green	15 45 20 15		pF	V <sub>F</sub> =0V;f=1MHz
V <sub>F</sub>	Forward Voltage	High Efficiency Red Super Bright Red Yellow Green	2.0 1.85 2.1 2.2	2.5 2.5 2.5 2.5	V	I <sub>F</sub> =20mA
I <sub>R</sub>	Reverse Current	All		10	uA	V <sub>R</sub> = 5V

## Absolute Maximum Ratings at $T_A=25^\circ\text{C}$

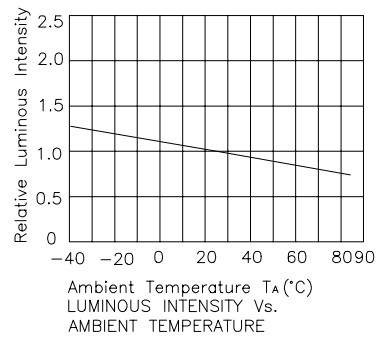
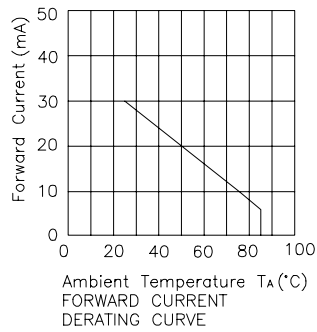
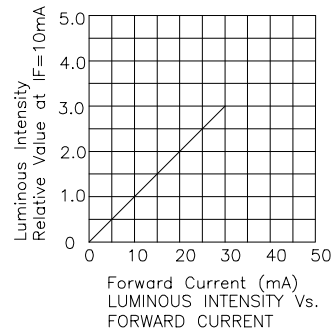
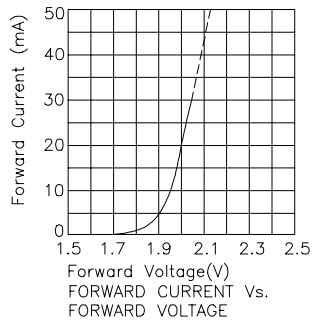
Parameter	High Efficiency Red	Super Bright Red	Yellow	Green	Units
Power dissipation	105	100	105	105	mW
DC Forward Current	30	30	30	25	mA
Peak Forward Current [1]	160	155	140	140	mA
Reverse Voltage	5	5	5	5	V
Operating/Storage Temperature	-40°C To +85°C				
Lead Solder Temperature [2]	260°C For 5 Seconds				

Notes:

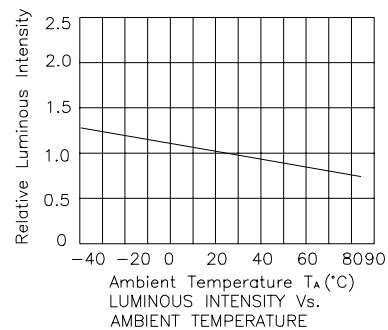
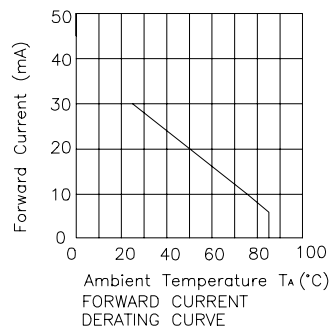
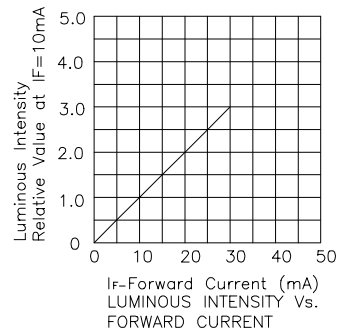
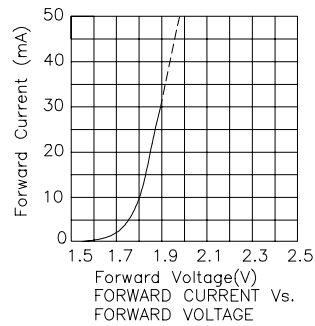
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



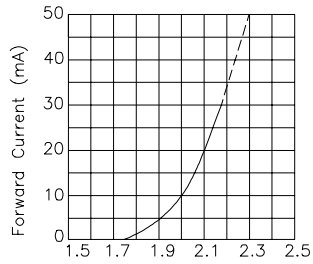
## High Efficiency Red



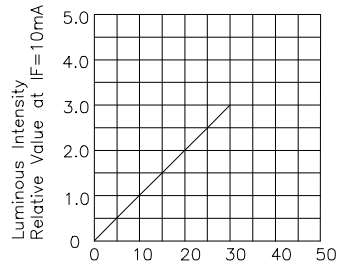
## Super Bright Red



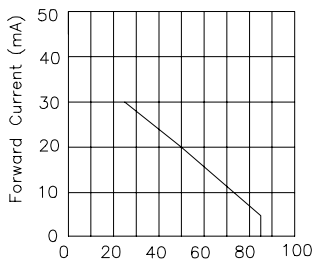
## Yellow



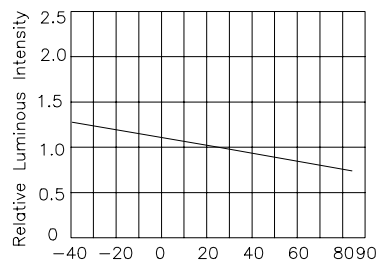
Forward Voltage(V)  
FORWARD CURRENT Vs.  
FORWARD VOLTAGE



Forward Current (mA)  
LUMINOUS INTENSITY Vs.  
FORWARD CURRENT

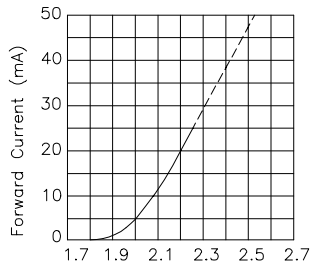


Ambient Temperature  $T_A$ (°C)  
FORWARD CURRENT  
DERATING CURVE

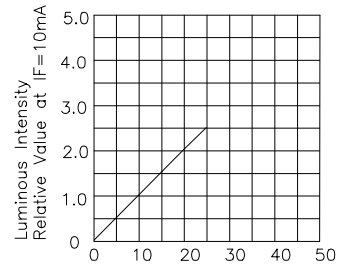


Ambient Temperature  $T_A$ (°C)  
LUMINOUS INTENSITY Vs.  
AMBIENT TEMPERATURE

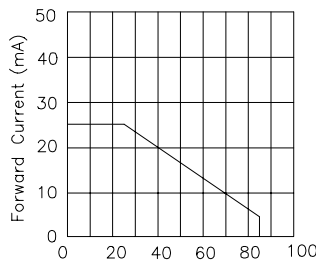
## Green



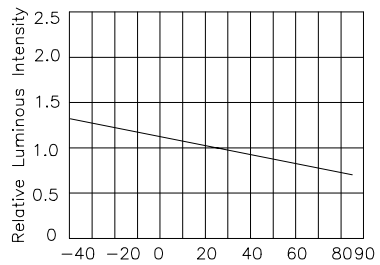
Forward Voltage(V)  
FORWARD CURRENT Vs.  
FORWARD VOLTAGE



Forward Current (mA)  
LUMINOUS INTENSITY Vs.  
FORWARD CURRENT



Ambient Temperature  $T_A$ (°C)  
FORWARD CURRENT  
DERATING CURVE



Ambient Temperature  $T_A$ (°C)  
LUMINOUS INTENSITY Vs.  
AMBIENT TEMPERATURE